Onsemi

Complementary Power Transistors

DPAK For Surface Mount Applications

MJD31 (NPN), MJD32 (PNP)

Designed for general purpose amplifier and low speed switching applications.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves
- Straight Lead Version in Plastic Sleeves ("1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series
- Epoxy Meets UL 94, V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

| Symbol V _{CEO} | Max | Unit Vdc |
|-----------------------------------|---|--|
| V _{CEO} | 10 | Vde |
| | 40 100 | vuc |
| V _{CB} | 40 100 | Vdc |
| V_{EB} | 5.0 | Vdc |
| I _C | 3.0 | Adc |
| I _{CM} | 5.0 | Adc |
| Ι _Β | 1.0 | Adc |
| P _D | 15 0.12 | W W/°C |
| P _D | 1.56 0.012 | W W/°C |
| T _J , T _{stg} | -65 to +150 | °C |
| HBM | 3B | V |
| MM | M3 | V |
| | V _{EB} I _C I _D P _D P _D T _J , T _{stg} HBM MM | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ |

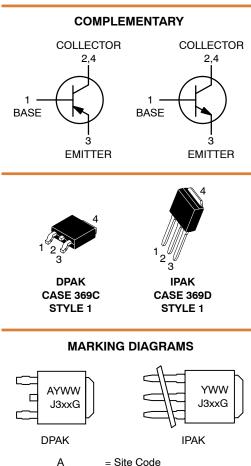
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------|-----|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 8.3 | °C/W |
| Thermal Resistance, Junction-to-Ambient* | R_{\thetaJA} | 80 | °C/W |
| Lead Temperature for Soldering Purposes | ΤL | 260 | °C |

*These ratings are applicable when surface mounted on the minimum pad sizes recommended.

SILICON **POWER TRANSISTORS** 3 AMPERES 40 AND 100 VOLTS **15 WATTS**



= Site Code

= Year = Work Week

Y

WW

хх G

= 1, 1C, 2, or 2C

= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

| Characteristic | Symbol | Min | Мах | Unit |
|---|-----------------------|-----------|----------|------|
| OFF CHARACTERISTICS | | | | |
| Collector–Emitter Sustaining Voltage (Note 1) ($I_C = 30 \text{ mAdc}, I_B = 0$) MJD31, MJD32 MJD31C, MJD32C | V _{CEO(sus)} | 40 100 | | Vdc |
| Collector Cutoff Current (V _{CE} = 40 Vdc, I _B = 0) | I _{CEO} | | | μAdc |
| MJD31, MJD32 (V _{CE} = 60 Vdc, I _B = 0) MJD31C, MJD32C | | _ | 50 50 | |
| Collector Cutoff Current (V _{CE} = Rated V _{CEO} , V _{EB} = 0) | ICES | _ | 20 | μAdc |
| Emitter Cutoff Current ($V_{BE} = 5 \text{ Vdc}, I_C = 0$) | I _{EBO} | _ | 1 | mAdc |
| ON CHARACTERISTICS (Note 1) | | | | |
| DC Current Gain ($I_C = 1 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$) ($I_C = 3 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$) | h _{FE} | 25 10 | _ 50 | |
| Collector–Emitter Saturation Voltage $(I_C = 3 \text{ Adc}, I_B = 375 \text{ mAdc})$ | V _{CE(sat)} | _ | 1.2 | Vdc |

Small-Signal Current Gain h_{fe} 20 $(I_{C} = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1 \text{ kHz})$ _

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

V_{BE(on)}

 f_{T}

Vdc

MHz

1.8

_

_

3

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 2. f_T = $|h_{fe}| \bullet f_{test}$.

Base-Emitter On Voltage

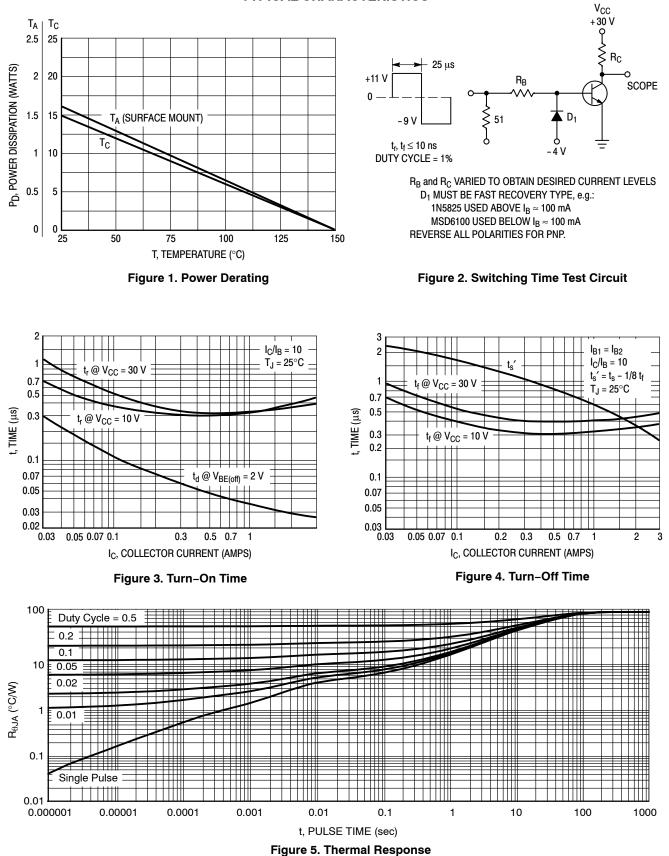
 $(I_C = 3 \text{ Adc}, V_{CE} = 4 \text{ Vdc})$

DYNAMIC CHARACTERISTICS

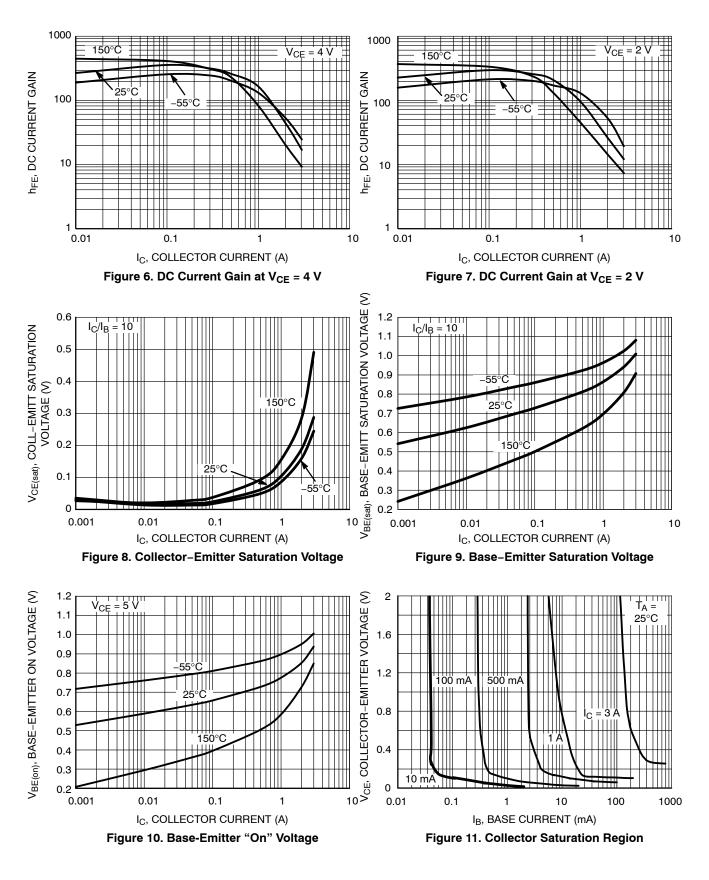
Current Gain - Bandwidth Product (Note 2)

 $(I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1 \text{ MHz})$

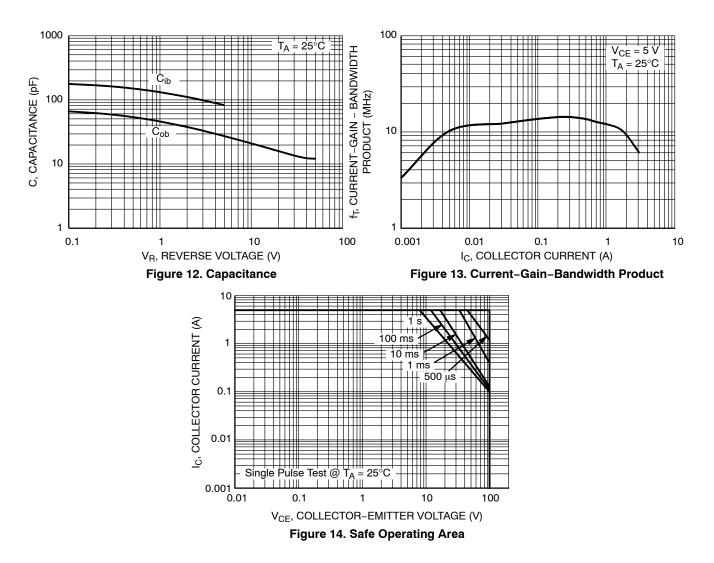
TYPICAL CHARACTERISTICS



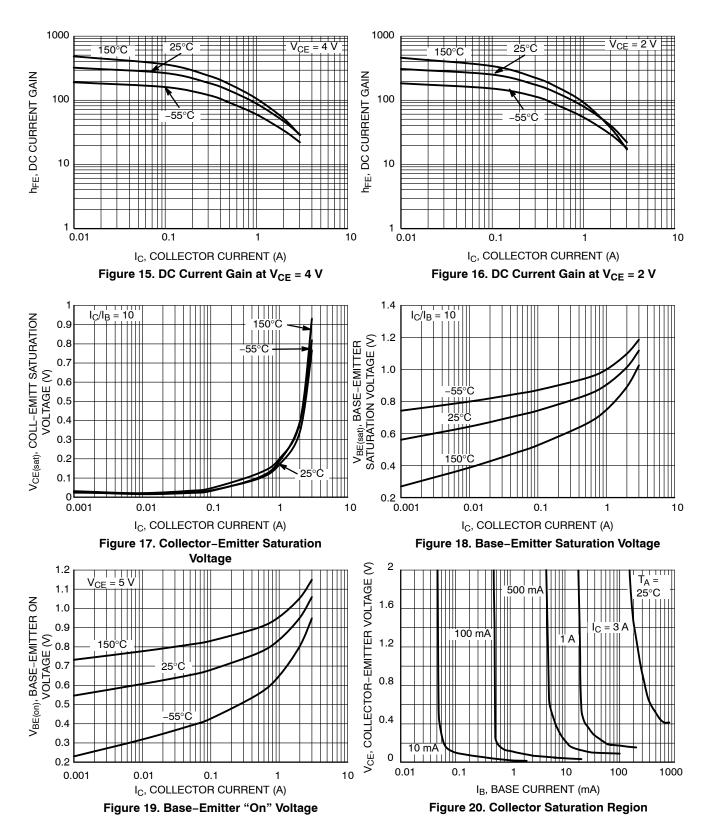
TYPICAL CHARACTERISTICS – MJD31, MJD31C (NPN)



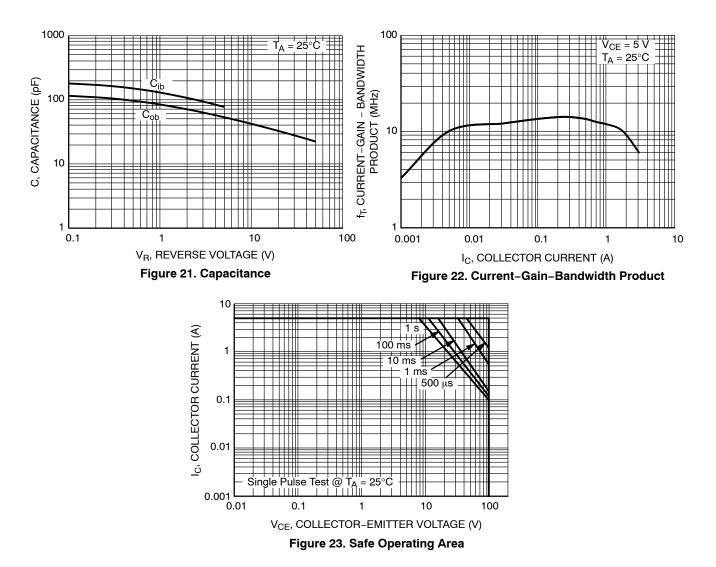
TYPICAL CHARACTERISTICS - MJD31, MJD31C (NPN)



TYPICAL CHARACTERISTICS - MJD32, MJD32C (PNP)



TYPICAL CHARACTERISTICS



ORDERING INFORMATION

| Device | Package Type Package | | Shipping [†] | |
|---------------|----------------------|------|-----------------------|--|
| MJD31CG | DPAK (Pb-Free) | 369C | 75 Units / Rail | |
| NJVMJD31CG* | DPAK (Pb–Free) | 369C | 75 Units / Rail | |
| MJD31C1G | IPAK (Pb-Free) | 369D | 75 Units / Rail | |
| MJD31CRLG | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel | |
| NJVMJD31CRLG* | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel | |
| MJD31CT4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| NJVMJD31CT4G* | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| MJD31T4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| NJVMJD31T4G* | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| MJD32CG | DPAK (Pb-Free) | 369C | 75 Units / Rail | |
| NJVMJD32CG* | DPAK (Pb-Free) | 369C | 75 Units / Rail | |
| MJD32CRLG | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel | |
| MJD32CT4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| NJVMJD32CT4G* | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| MJD32RLG | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel | |
| MJD32T4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |
| NJVMJD32T4G* | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel | |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.

DATE 15 DEC 2010



IPAK CASE 369D-01 **ISSUE C** С в -SCALE 1:1 v Ε R 7 4 Α S 2 3 1 -T-7 SEATING κ ۱I J F н D 3 PL G 🖛 🔶 0.13 (0.005) 🔘 T

> STYLE 3: PIN 1. ANODE

CATHODE
ANODE

4. CATHODE

COLLECTOR

STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER

4.

STYLE 2: PIN 1. GATE

STYLE 6: PIN 1. MT1 2. MT2 3. GATE

4. MT2

DRAIN
SOURCE

4. DRAIN

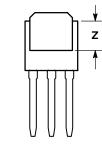
STYLE 1: PIN 1. BASE

2. COLLECTOR

EMITTER
COLLECTOR

STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE

4. ANODE



STYLE 4: PIN 1. CATHODE

ANODE
GATE

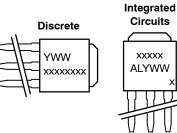
4. ANODE

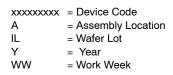
| | INCHES MILLIME | | | IETERS | |
|-----|----------------|-------|----------|--------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.235 | 0.245 | 5.97 | 6.35 | |
| В | 0.250 | 0.265 | 6.35 | 6.73 | |
| С | 0.086 | 0.094 | 2.19 | 2.38 | |
| D | 0.027 | 0.035 | 0.69 | 0.88 | |
| Е | 0.018 | 0.023 | 0.46 | 0.58 | |
| F | 0.037 | 0.045 | 0.94 | 1.14 | |
| G | 0.090 BSC | | 2.29 BSC | | |
| Н | 0.034 | 0.040 | 0.87 | 1.01 | |
| J | 0.018 | 0.023 | 0.46 | 0.58 | |
| к | 0.350 | 0.380 | 8.89 | 9.65 | |
| R | 0.180 | 0.215 | 4.45 | 5.45 | |
| S | 0.025 | 0.040 | 0.63 | 1.01 | |
| V | 0.035 | 0.050 | 0.89 | 1.27 | |
| Ζ | 0.155 | | 3.93 | | |

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

NOTES:

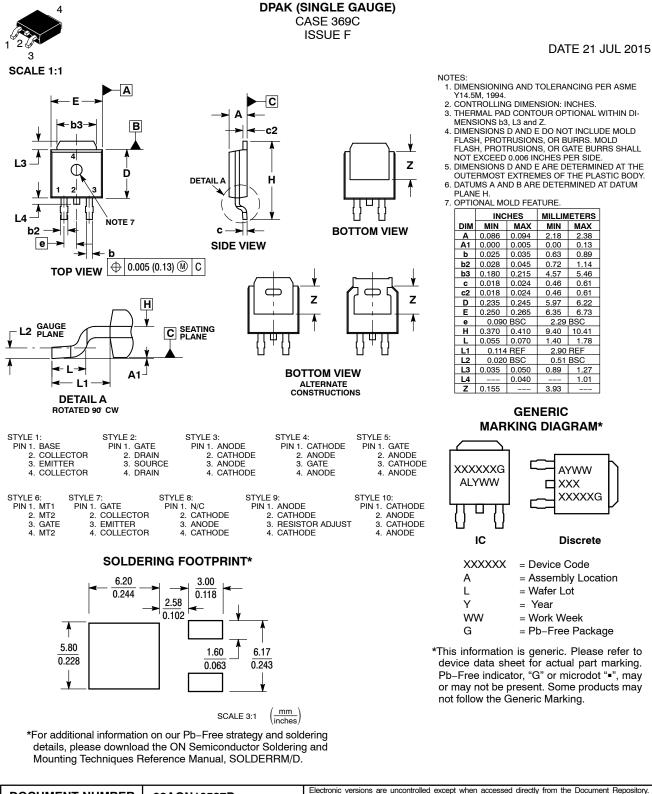
MARKING DIAGRAMS





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|---|-----------------------------|---|-------------|--|--|--|
| DESCRIPTION: | IPAK (DPAK INSERTION MOUNT) | | PAGE 1 OF 1 | | | |
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